



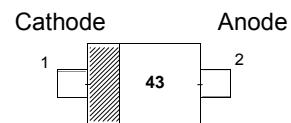
迈拓电子
MAITUO ELECTRONIC

BAS40WT SURFACE MOUNT SCHOTTKY BARRIER DIODE



Features

- Low forward voltage
- Fast switching



Marking Code: "43"

SOD-523

Absolute Maximum Ratings ($T_a = 25^\circ\text{C}$)

Parameter	Symbol	Value	Unit
Repetitive Peak Reverse Voltage	V_{RRM}	40	V
DC Blocking Voltage	V_R	40	V
Forward Continuous Current	I_F	200	mA
Peak Forward Surge Current (at $t_p = 8.3 \text{ ms}$)	I_{FSM}	600	mA
Junction Temperature	T_J	150	$^\circ\text{C}$
Storage Temperature Range	T_{Stg}	-55 to +150	$^\circ\text{C}$

Characteristics at $T_a = 25^\circ\text{C}$

Parameter	Symbol	Min.	Max.	Unit
Forward Voltage at $I_F = 1 \text{ mA}$ at $I_F = 40 \text{ mA}$	V_F V_F	- -	0.38 1	V V
Reverse Current at $V_R = 30 \text{ V}$	I_R	-	200	nA
Reverse Breakdown Voltage at $I_R = 10 \mu\text{A}$	$V_{(BR)R}$	40	-	V
Reverse Recovery Time at $I_F = I_R = 10 \text{ mA}$ to $I_R = 1 \text{ mA}$, $R_L = 100 \Omega$	t_{rr}	-	5	ns
Capacitance at $V_R = 0 \text{ V}$, $f = 1 \text{ MHz}$	C_j	-	5	pF



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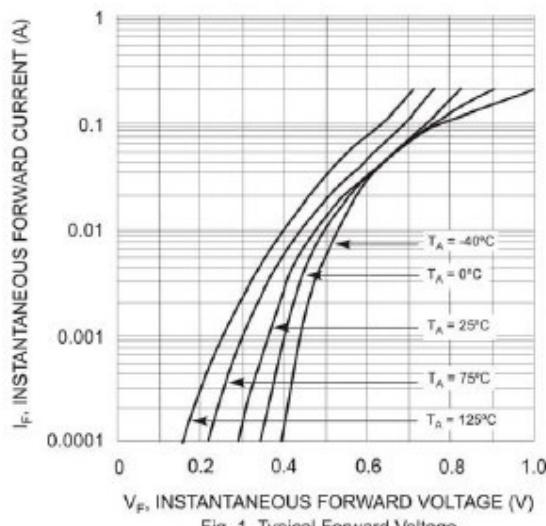


Fig. 1 Typical Forward Voltage

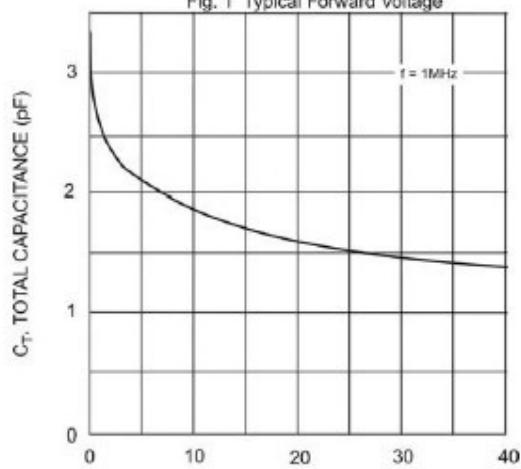


Fig. 3 Typical Capacitance

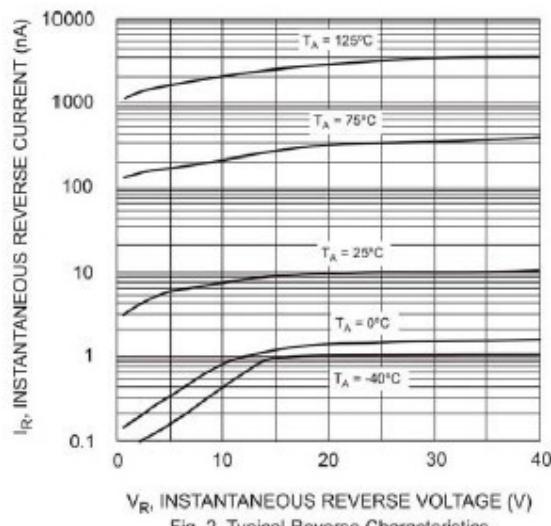


Fig. 2 Typical Reverse Characteristics

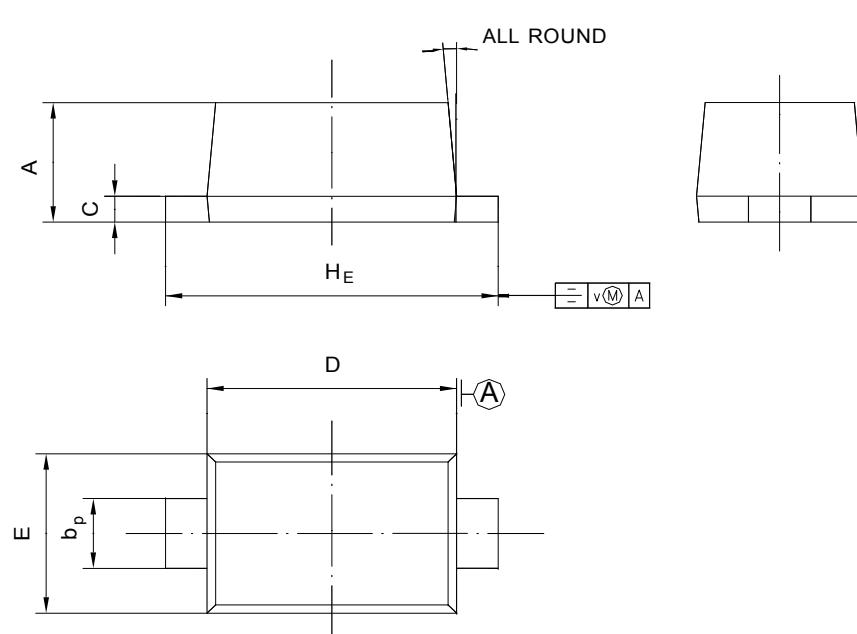


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PACKAGE OUTLINE

Plastic surface mounted package; 2 leads

SOD-523



UNIT	A	b _p	C	D	E	H _E	V	∠
mm	0.68 0.58	0.4 0.3	0.135 0.100	1.25 1.15	0.85 0.75	1.7 1.5	0.1	5°